

1200V SiC Schottky Diode

FEATURES

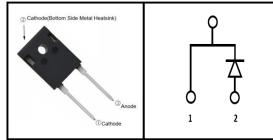
- Low Conduction and Swiitch Loss
- Positive Temperature Coefficient on VF
- Temperature Independent Switching Behavior
- Fast Reverse Recovery
- High Surge Current Capability
- Pb-free lead plating

BENEFITS

- Higher System Efficiency
- Parallel Device Convenience
- High Temperature Application
- High Frequency Operation
- Hard Switching & High Reliability
- Environmental Protection

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)
- Solar/ Wind Renewable Energy
- Power Inverters
- Motor Drives





Device Marking and Package Information				
Device	Package	Marking		
C2S120F020B	TO-247-2L	C2S120F020B		

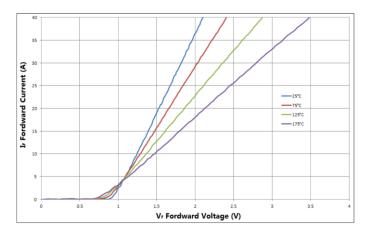
Absolute Maximum Ratings T _C = 25°C, unless otherwise noted					
Parameter	Symbol	Test Conditions	Value	Unit	
Peak Repetitive Reverse Voltage	V_{RRM}	T _J = 25°C	1200	V	
Peak Reverse Surge Voltage	V _{RSM}	T _J = 25°C	1200	V	
DC Blocking Voltage	V _R	T _J = 25°C	1200	V	
Continuous Forward Current	I _F	T _J ≤ 135°C	20	Α	
Repetitive Peak Forward Surge Current	I _{FRM}	$T_C = 25^{\circ}C$, $T_P = 8.3$ ms Half Sine Wave	150	Α	
Maximum Case Temperature	T _C		135	°C	
Operating Junction and Storage Temperature	T _J , T _{stg}		-55~175	°C	

Thermal Resistance				
Parameter	Symbol	Value	Unit	
Thermal Resistance, Junction-to-Case	R _{thJC}	0.65	°C/W	



Specifications T _J = 25°C, unless otherwise noted						
Daramatar	Symbol	Test Conditions	Value		I India	
Parameter		rest Conditions	Тур.	Max.	Unit	
Forward Voltage	V _F	I _F = 20A, T _J = 25°C	1.6	1.8	V	
		$I_F = 20A, T_J = 175^{\circ}C$	2.25	2.5	V	
Reverse Current	I _R	V _R =1200V, T _J = 25°C	5	20	μΑ	
		V _R =1200V, T _J = 175°C	30	200	μΑ	
Total Capacitive Charge	Q _c	$I_F = 20A$, di/dt =200A / μ s $V_R = 1200V$, $T_J = 25$ °C	59		nC	
Total Capacitance	С	$V_R = 0V, T_J = 25^{\circ}C, f = 1 \text{ MHz}$	1280			
		V _R =400V, T _J = 25°C, , f =1 MHz	95		pF	
		V _R =800V, T _J = 25°C, , f =1 MHz	77			





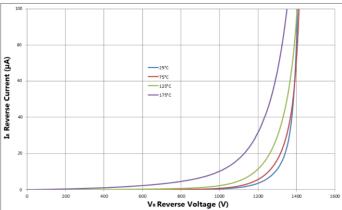
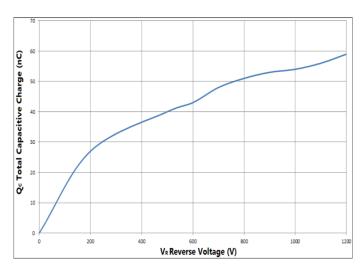


Fig. 1 Forward Characteristics

Fig. 2 Reverse Characteristics



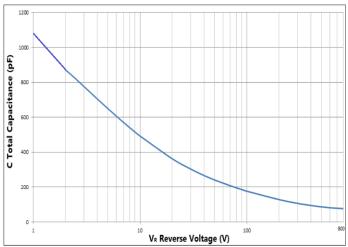


Fig. 3 Total Capacitance Charge vs. Reverse Voltage

Fig. 4 Total Capacitance vs. Reverse Voltage

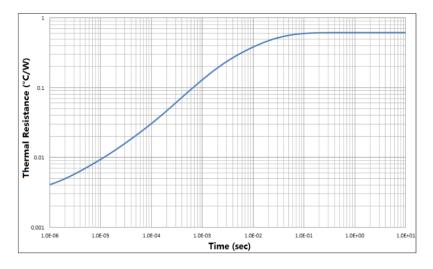
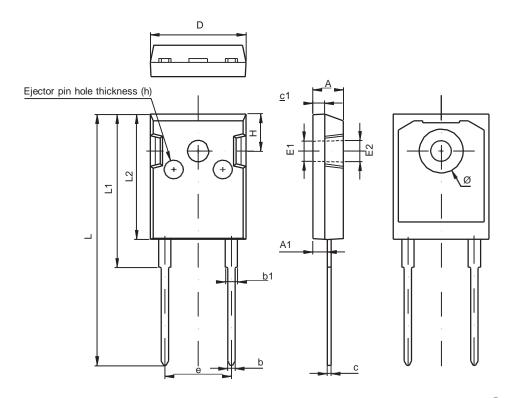


Fig. 5 Transient Thermal Impedance



TO-247-2



TO-247-2L DIMENSIONS

SYMBOL	DIMENSIONS I	N MILLIMETERS	DIMENSIONS IN INCHES			
	MIN.	MAX.	MIN.	MAX.		
A	4.850	5.150	0.191	0.200		
A1	2.200	2.600	0.087	0.102		
b	1.000	1.400	0.039	0.055		
b1	1.800	2.200	0.071	0.087		
С	0.500	0.700	0.020	0.028		
c1	1.900	2.100	0.075	0.083		
D	15.450	15.750	0.608	0.620		
E1	3.50	3.500 Ref.		0.138 Ref.		
E2	3.60	3.600 Ref.		0.142 Ref.		
L	40.900	41.300	1.610	1.626		
L1	24.800	25.100	0.976	0.988		
L2	20.300	20.600	0.799	0.811		
Ø	7.100	7.300	0.280	0.287		
е	10.900 Typ.		0.429 Typ.			
Н	5.980 Typ.		0.235 Typ.			
h	0.000	0.300	0.000	0.012		



Disclaimer

All product specifications and data are subject to change without notice.

For documents and material available from this datasheet, Suzhou Convert does not warrant or assume any legal liability or responsibility for the accuracy, completeness of any product or technology disclosed hereunder.

No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document or by any conduct of Suzhou Convert.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless. Customers using or selling Suzhou Convert products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Suzhou Convert for any damages arising or resulting from such use or sale.

Suzhou Convert disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Suzhou Convert's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

Suzhou Convert SemiConductor CO., Ltd. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.

In the event that any or all Suzhou Convert products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.

Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. Suzhou Convert believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.